

CHEM-E5125

Thin Film Technolgy - Introduction Functional Materials Major

(5 credits)

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Contents

Terminology

- Motivation: Why thin films?
- Applications
- Deposition methods thin film process
- Examples
 - Microstructure
 - Composition
 - Properties resistivity
 - Properties Stress
 - Mechanical
- Interface



Terminology

- Film or coating is material which is restricted in one dimension
- Substrate is solid material supporting the film
- Thickness
 - Atomic level:
 - 2-5 atom layers on the surface ($\approx 0.2 0.5$ nm)
 - over 10 atomic layers (≈ 1 nm) is bulk
 - Technically
 - 1nm 10 µm
 - Needed layer thickness, which is needed to:
 - protect substrate
 - Wanted functionality of the coating





Mikko Ritala Thin Films

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Motivations - why thin films?

- Interaction of materials (commonly) via surface
- Modification of material properties added functionality
 Functional thin films
- Market of thin films and coatings
 - volume about about 1% of GNP
 - common in all areas of industry
 - Electronics
 - Transport
 - Energy
 - Building
 - Bio-technology



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Hardness, protection and wear

Diamond-like carbon









Art & Decoration



Titanium Nitride, Titanium Dioxide





Function and utility



Titanium Dioxide: Photocatalytic activity



Indium Tin Oxide, ITO: Defrosting coating



Microelectromechanical systems, MEMS



RAITH150 Mag = 800 X EHT = 500 kV Signal A = 8E2 Date 11 Feb 2010

Applications of thin films

- Electronic components
 - semiconducting, dielectric, insulating, conductors, barriers...
- Electronic displays
 - LCrystalD, LED, ELuminescent, Echorimc, transparent conductive...
- Photo voltaic
- Optical coatings
- Magnetic Films for Data Storage
- Optical data storage
- Antistatic coatings
- Hard protective coatings
- Decorative films
- Decorative and wear-resistant (decorative/functional) coatings
- Permeation barriers for moisture and gases
- Corrosion resistant films
- Coating of engine turbine blades
- Wear and erosion resistant (hard) coatings (tool coatings)
- Dry film lubricants
- Thin-walled freestanding structures
- etc.



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Coating technologies

Aalto University School of Chemical Engineering
 Table 1.1: Vacuum deposition techniques [10]
 Handbook of Deposition Technologies for Films and Coatings - Science, Applications and Technology (3rd Edition)

Atomistic deposition	Particulate deposition	Bulk coatings	Surface modification
Electrolytic environment	Thermal spraying	Wet processes	Chemical conversion
Electroplating	Plasma spraying	Painting	Electrolytic
Electroless plating	D-gun	Dip coating	Anodization (oxide)
Fused salt electrolysis	Flame spraying	Electrostatic spraying	Fused salts
Chemical displacement	Fusion coatings	Printing	Chemical-liquid
Vacuum environment	Thick film ink	Spin coating	Chemical vapor
Vacuum evaporation	Screen printing	Cladding	Thermal
Ion beam deposition	Jet printing	Explosive	Plasma
Laser ablation	Enameling	Roll bonding	Leaching
Molecular beam epitaxy	Electrophoretic	Overlaying	Mechanical
Cathodic arc	Impact plating	Weld coating	Shot peaning
Vacuum polymer deposition			Thermal
Plasma environment			Surface enrichment
Sputter deposition			Diffusion from bulk
Activated reactive evaporation			Sputtering
Cathodic arc			Ion implantation
Plasma polymerization			Self-assembly
lon plating			-
Chemical vapor environment			
Plasma enhanced			
Atomic layer			
deposition			
Reduction			
Decomposition			
Spray pyrolysis			
Liquid phase epitaxy			11

Coating technologies in this cource

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 Edited by: Martin, Peter M. © 2010 William Andrew Publishing

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The thin film process





SUBSTRATE

component

tool











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SURFACE PROCESSES

•adsorption of film forming atoms
•desorption of film forming atoms
•film nucleation and coalescence
•impurity adsorption, desorption, incorporation

ion bombardmentenergy from depositing specieexternal heating





ANNEALING
inert atmosphere
reactive atmosphere
chemical reactions
phycical reactions
global vs. local

ANALYSIS

physical chemical electrical optical









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PVD: Physical Vapor Deposition



CVD: Chemical Vapor Deposition





Deposition viewpoint: PVD

PVD activation methods:

- open resistive heating
- electron beam heating
- equilibrium source heating
- argon ion bombardment
- arc discharge
- laser beam bombardment

- evaporation (thermal)
- evaporation (e-beam)
- molecular beam epitaxy MBE
- sputtering

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- evaporation+ionization
 - ablation



Sputtering variables Deposition of "optimal" AIN

Power supp1y	Power (kW)	Pressure (mTorr)	N ₂ (%)	d (mm)	Temp. (°C)	Base P (Torr)	fwhm (°)
dc	2-6	1-5	100	?	500	1×10^{-8}	2-3
ſſ	1.0	3.4	33	50	315	$1 imes 10^{-8}$	1
dc	?	2.7	?	?	?	3×10^{-9}	?
dc	0.2	1	100	40	200	?	2.3
ſſ	0.4	5	50	50	100	$1 imes 10^{-8}$	3.3
ıf	0.3	30	100	75	350	?	?
dc	0.1	6	100	35	250	$8 imes10^{-6}$	11
ıf	0.2	3	50	40	50	?	2.5



Journal of The Electrochemical Society, 146 (2) 691-696 (1999)

Deposition viewpoint: CVD

- thermal CVD
- PECVD (a.k.a. PACVD) plasma enhanced
- MOCVD (metal organic)
- HDP-CVD (High Density Plasma)
- HW-CVD (Hot Wire)
- Photo-CVD
- LACVD (Laser Assisted)
- remote-PECVD
- low frequency (55 kHz; 400 kHz)
- µw-CVD (microwave)



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Film viewpoint

- amorphous
- nanocrystalline
- microcrystalline
- polycrystalline
- epitaxial
- textured



(a) Crystalline

(b) Polycrystalline

(c) Amorphous

Allen: MEMS



Texture coefficient TC





Journal of The Electrochemical Society, 146 (2) 691-696 (1999) 27

Film thickness and texture, TiN





Aalto Journal of The Electrochemical Society, **146** (2) 691-696 (1999) Engineering

Film viewpoint cont'd

- stoichiometric
- hydrogenated
- porous/dense
- reacted
- doped

metals, oxides: 1-5% dopant polysilicon: 10⁻³...10⁻⁶ dopant



Doped oxides SiO_xF_y

	FTMS	FTES	TEOS/O3
Deposition rate (nm/min)	31	22	_
Fluorine concentration $(\times 10^{21} \text{ atoms/cm}^3)$	5.4	5.3	-
Carbon concentration ^a ($\times 10^{21}$ atoms/cm ³)	1.1	2.0	-
Refractive index	1.390	1.403	1.451
Etching rate (nm/min) (1:30 buffered HF)	202	215	120
Si-O peak position (cm ⁻¹) (FTIR spectra)	1083	1083	1075

^a At the depth of 0.2 μ m.

FTES fluorotriethoxysilane FTMS fluorotrimethoxysilane TEOS tetraethyl orthosilicate

T. Homma / Materials Science and Engineering R23 (1998) 243–285



Film viewpoint cont'd

- low resistivity
- low impurity concentration
- low stress
- free of moisture absorption
- small surface roughness
- low shrinkage
- good step coverage



Resistivity



 $\rho = \rho_{\text{residual}} + \rho_{\text{temp}}$

Linear TCR above Debye temperature (typically 200-400K)

Annealing defects at elevated temperature lowers resistance (no reaction with underlying film/substrate)

Murarka











Resistivity: impurity effects



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Stress and Poisson ratio



Stress $\sigma = F/A$ longitudinal strain $\varepsilon = \Delta L/L$ transverse strain $\varepsilon_t = \Delta D/D$ Young's modulus $E = \sigma/\varepsilon$

Poisson ratio $v = -\epsilon_t / \epsilon$ For many metals $v \approx 0.3$ Kovacs



Stress and strain





Elastic/Linear region, Hooke's law valid: $\sigma = \varepsilon E$

Plastic I: permanent deformation

Yield strength: 0.2% shifted curve intersects stress-strain curve

Maximum stress = tensile stress

Plastic II: necking occurs

Toughness = area below stress-strain curve = energy absorbed

Hardness: resistance to plastic deformation

Murarka

Terminology 1

- Ductile materials (many metals) will bend before breaking. Tensile stress is greater than yield stress.
- Brittle materials (like silicon) will break suddenly and without warning. Tensile stress is roughly the same as yield stress



Sources of stress: $\sigma = \sigma_i + \sigma_{th}$

- intrinsic:
 - film microstructure (grain size, orientation)
 - defects and impurities in film
 - volume changes
 - lattice mismatch (important in epitaxy)
- thermal mismatch:

$$\sigma = E_{\rm f}/(1-\nu) \times (\alpha_{\rm f} - \alpha_{\rm s}) \times \Delta T$$



Volume changes

 $xM + ySi \rightarrow M_xSi_y$,

the volume change $\triangle V(\%)$ is given by

$$\triangle \mathbf{V} = \frac{(\mathbf{x}\mathbf{V}_M + \mathbf{y}\mathbf{V}_{Si}) - \mathbf{V}(\mathbf{M}_x\mathbf{S}\mathbf{i}_y)}{(\mathbf{x}\mathbf{V}_M + \mathbf{y}\mathbf{V}_{Si})} \times 100,$$

In silicide formation, negative volume change \rightarrow tensile stress

In thermal oxidation, positive volume change \rightarrow compressive stress





Sputtering pressure affects stress



At low pressures sputtered films are compressively stressed;

above critical pressure, tensile stressed

At low pressure there is large momentum transfer resulting in energetic argon atoms that will densify the film by knockon (peening) or get implanted in the film

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Mechanical and tribological properties

Table 1 Mechanical and tribological properties of commercially available hard coatings.

	TiN	TiCN	TiC	TiAlN	CrN	Al ₂ O ₃
Deposition method	PVD/CVD	PVD/CVD	CVD	PVD	PVD/CVD	CVD/PVD
Typical thickness (µm)	1-5	1-5	1-5	1-5	1-15	1-5
Hardness (HV 0.05) ^a	2300	3000	3100	3000	1 900	2100 (HV 0 1)
Oxidation temperature (°C) ^b	> 450	> 350	> 350	> 700	> 600	2100 (111 0.1)
Friction coefficient ^a	0.5 - 0.7	0.5-0.7	0.5-0.7	0.6-0.8	0.5-0.8	0.7-0.9
Abrasive wear resistance	+ +	+++	+ + +	+ + +	++	++
Adhesive wear resistance against steel	+ +	+/++	+	+ +	÷ +	+ + +
Resistance against wear by diffusion	+ +	+	+	+++	÷ ÷	+ + +
Corrosion protection of base material ^d	+	+	+	+	+ +	+



Mechanical and tribological properties cont'd

Table 2

Mechanical and tribological properties of MoS₂, diamond, and different DLC films.

	MoS ₂	Me-DLC	DLC	Si-DLC	ta-C	Diamond
Deposition method	PVD	PVD	PECVD	PECVD	PVD	CVD
Thickness (µm)	0.1 - 1	1-5	1-5	1-5	1-3	3-10
Hardness (HV 0.05)*	< 500	8001800	1 5003 500	600-1000	30007000	10000
Typical values for compressive stress (GPa)		0.1-1	1-3	1	2–6	
Temperature of transformation (°C) ^b	350	350	400	500	450	> 600
Friction coefficient ^c	0.02-0.1	< 0.2	0.15 - 0.2	0.07 - 0.15	0.15-0.2	< 0.2
Abrasive wear resistance		+	+ + +	+	+ + + +	+ + + +
Adhesive wear resistance against steel		+ +	+ + +	+ +	+ + +	(+++) only with good cooling
Corrosion protection of base material ^d		+	+ + +	+ + +	+ + +	+++



Interfaces



